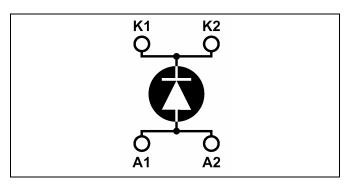
APTDF400U120

Single diode Power Module

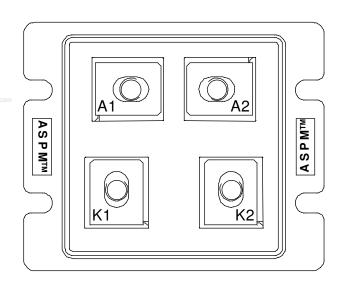
$$V_{CES} = 1200V$$

 $I_{C} = 400A @ Tc = 80^{\circ}C$



Application

- Anti-Parallel diode
 - Switchmode Power Supply
 - Inverters
- Snubber diode
- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers
- Electric vehicles



Features

- Ultra fast recovery times
- Soft recovery characteristics
- Very low stray inductance
- High blocking voltage
- High current
- Low leakage current

Benefits

- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance

Absolute maximum ratings

Symbol	Parameter			Max ratings	Unit
V_R	Maximum DC reverse Voltage			1200	V
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200	V
$I_{F(AV)}$	Maximum Average Forward	Duta1- 500/	$T_c = 25^{\circ}C$	450	
	Current	Duty cycle = 50%	$T_c = 80^{\circ}C$	400	A
I _{F(RMS)}	RMS Forward Current		750	Α	
I_{FSM}	Non-Repetitive Forward Surge Current		$T_j = 25^{\circ}C$	5000	

🌄 CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handing Procedures Should Be Followed.



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Electrical Characteristics All ratings @ $T_j = 25$ °C unless otherwise s					ise spe	ecified	
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
	Diode Forward Voltage	$I_{\rm F} = 500 {\rm A}$				2.5	
V_{F}		$I_F = 1000A$			2.5		V
		$I_F = 500A$	$T_{\rm j} = 150^{\circ}{\rm C}$			2.0	
T	Maximum Reverse Leakage Current	$V_R = 1200V$	$T_j = 25^{\circ}C$			2500	۸
I_{RM}		$\mathbf{v}_{\mathrm{R}} = 1200 \mathbf{v}$	$T_{j} = 125^{\circ}C$			5000	μΑ
C_{T}	Junction Capacitance	$V_{R} = 200V$			600		pF

Dynamic Characteristics

·	Characteristic	Test Conditions		Min	Typ	Max	Unit
t _{rr1}	Reverse Recovery Time	$I_F=1A, V_R=30V$ $di/dt = 15A/\mu s$	$T_j = 25^{\circ}C$		90		
t _{rr2}		$I_F = 500A$	$T_j = 25^{\circ}C$		110		ns
t _{rr3}		$V_R = 650V$ di/dt=1000A/ μ s	$T_j = 100^{\circ}C$		175		
$t_{\rm fr1}$	Forward Recovery Time		$T_j = 25^{\circ}C$		220		ns
t _{fr2}			$T_{\rm j} = 100^{\circ}{\rm C}$		220		113
I_{RRM1}	- Reverse Recovery Current		$T_j = 25^{\circ}C$		70		A
I_{RRM2}			$T_{\rm j} = 100^{\circ}{\rm C}$		120		11
Q_{rr1}	- Reverse Recovery Charge	$I_F = 500A$ $V_R = 650V$	$T_j = 25^{\circ}C$		10		μC
Q_{rr2}			di/dt=1000A/µs	$T_j = 100^{\circ}C$		30	
$V_{\rm fr1}$	Forward Recovery Voltage	·	$T_j = 25^{\circ}C$		26		V
$V_{\rm fr2}$			$T_j = 100^{\circ}C$		26		•
d _{IM/dt}	Rate of Fall of Recovery Current		$T_j = 25^{\circ}C$		1200		A/μs
₩IM/dt	rate of Fair of Recovery Current		$T_j = 100$ °C		800		12,40

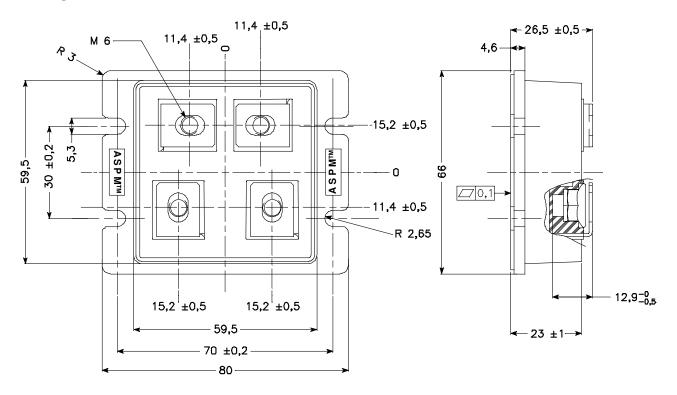
Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case					0.08	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, I isol<1mA, 50/60Hz			2500			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature	-40		100			
Torque	Mounting torque	To heatsink	M5	2.5		3.5	N.m
Torque	Woulding torque	For terminals	M6	3		4	19.111
Wt	Package Weight					250	g





Package outline



APT reserves the right to change, without notice, the specifications and information contained herein

APT's products are covered by one or more of U.S patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522 5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. U.S and Foreign patents pending. All Rights Reserved.